

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

POWER OF ATTORNEY

Docket No.

90065.001020/17732.8011.0

Name of Applicant: Fairchild Semiconductor Corporation
Address of Applicant: 82 Running Hill Road
South Portland, ME 04106

Title: CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND
SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS

Serial No., if Any: 09/682,151
Filed: July 27, 2001

TO THE ASSISTANT COMMISSIONER FOR PATENTS

The Assistant Commissioner for Patents
Washington, D.C. 20231

Honorable Sir:
I hereby appoint:

Thomas R. FitzGerald, Reg. No. 26,730

as principal attorneys to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith.

Please direct all future correspondence to:

Thomas R. FitzGerald, Esq.
16 E. Main St., Suite 210
Rochester, New York 14614-1803
Tel (585) 454-2250
Fax (585) 454-6364

By:

P.D. Delva
Assistant Secretary

Dated: 27 August 2002

CERTIFICATE OF MAILING BY FIRST CLASS MAIL (37 CFR 1.8)

Applicant(s): Martin E. Kordes, et al.

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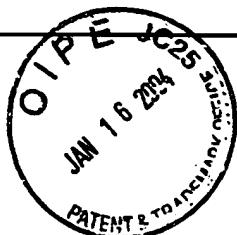
Examiner

Chris C. Chu

Group Art Unit

2815

Invention: **CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS**

I hereby certify that this Supplemental Declaration (executed, 4 pages)

(Identify type of correspondence)

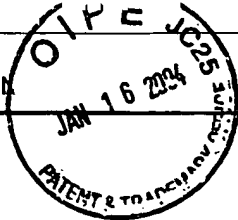
is being deposited with the United States Postal Service as first class mail in an envelope addressed to: The

Assistant Commissioner for Patents, Washington, D.C. 20231 on

April 10, 2003
(Date)Penny P. Clements

(Typed or Printed Name of Person Mailing Correspondence)


(Signature of Person Mailing Correspondence)**Note: Each paper must have its own certificate of mailing.**



Docket No.
90065.001020/17732.8011.00

Declaration and Power of Attorney For Patent Application

English Language Declaration

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS

the specification of which

(check one)

☐ is attached hereto.

☒ was filed on July 27, 2001 as United States Application No. or PCT International Application Number 09/682,151 and was amended on _____

(if applicable)

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, Section 119(a)-(d) or Section 365(b) of any foreign application(s) for patent or inventor's certificate, or Section 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate or PCT International application having a filing date before that of the application on which priority is claimed.

Prior Foreign Application(s)

Priority Not Claimed

None

(Number)

(Country)

(Day/Month/Year Filed)

☐

(Number)

(Country)

(Day/Month/Year Filed)

☐

(Number)

(Country)

(Day/Month/Year Filed)

☐

I her by claim the benefit under 35 U.S.C. Section 119(e) of any United States provisional application(s) listed below:

None	
(Application Serial No.)	(Filing Date)
(Application Serial No.)	(Filing Date)
(Application Serial No.)	(Filing Date)

I hereby claim the benefit under 35 U. S. C. Section 120 of any United States application(s), or Section 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of 35 U.S.C. Section 112, I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, C. F. R., Section 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application:

None		
(Application Serial No.)	(Filing Date)	(Status) (patented, pending, abandoned)
(Application Serial No.)	(Filing Date)	(Status) (patented, pending, abandoned)
(Application Serial No.)	(Filing Date)	(Status) (patented, pending, abandoned)

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith. *(list name and registration number)*


Thomas R. FitzGerald, Reg. No. 26,730

Send Correspondence to: Thomas R. FitzGerald, Esq.
16 E. Main Street, Suite 210
Rochester, New York 14614-1803

Direct Telephone Calls to: *(name and telephone number)*
(585) 454-2250

Full name of sole or first inventor Martin E. Kordesch
Sole or first inventor's signature <i>Martin E. Kordesch</i> Date 4-8-03
Residence 11 Circle Drive, The Plains, Ohio 45780
Citizenship United States of America
Post Office Address Same as above

Full name of second inventor, if any Howard D. Bartlow
Second inventor's signature <i>Howard D. Bartlow</i> Date 4-7-03
Residence 1211 Torrey Lane, Nampa, Idaho 83686
Citizenship United States of America
Post Office Address Same as above

Full name of third inventor, if any Richard L. W odin	
Third inventor's signature 	Date 4/4/03
Residence 5716 Galsworthy Court, Austin, Texas 78739	
Citizenship United States of America	
Post Office Address Same as above	

Full name of fourth inventor, if any	
Fourth inventor's signature	Date
Residence	
Citizenship	
Post Office Address	

Full name of fifth inventor, if any	
Fifth inventor's signature	Date
Residence	
Citizenship	
Post Office Address	

Full name of sixth inventor, if any	
Sixth inventor's signature	Date
Residence	
Citizenship	
Post Office Address	



**THE OFFICIAL DATE STAMP HEREON BY THE USPTO
ACKNOWLEDGES RECEIPT OF THE FOLLOWING:**

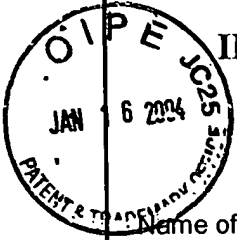
DATE MAILED: November 17, 2003 DOCKET No.: 90065.001020/XDEV1100
APPLICANT(S): Martin E. Kordes, et al.
SERIAL NO.: 09/682,151
FILING DATE: July 27, 2001

ENCLOSURE(S):

- 1.) Revocation of Power of Attorney (1 page)
- 2.) Certificate of First Class Mail (1 page)
- 3.) Return Receipt Acknowledgment Postcard
- 4.) *Copy of Change of Attorney Address (1 pg)*



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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE
REVOCATION OF POWER OF ATTORNEY

Docket No.

Name of Applicant: FAIRCHILD SEMICONDUCTOR CORPORATION

Address of Applicant: 82 Running Hill Road
South Portland, ME 04106

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TO THE COMMISSIONER FOR PATENTS

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Honorable Sir:

I hereby revoke the Power of Attorney given to:

The registered practioner(s) at Customer Number 25094

Dated: 11/5/03

By: Matthew Towse

Name Here: MATTHEW TOWSE

Title: CHIEF FINANCIAL OFFICER
Fairchild Semiconductor Corporation